

# Negative capacitance in multidomain ferroelectric superlattices

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Citation Report

#	ARTICLE	IF	CITATIONS
1	Negative Capacitance Behavior in a Leaky Ferroelectric. <i>IEEE Transactions on Electron Devices</i> , 2016, 63, 4416-4422.	1.6	108
2	Decrease in the double layer capacitance by faradaic current. <i>RSC Advances</i> , 2017, 7, 22501-22509.	1.7	36
3	Negative permittivity adjusted by SiO <sub>2</sub> -coated metallic particles in percolative composites. <i>Journal of Alloys and Compounds</i> , 2017, 725, 1259-1263.	2.8	64
4	Origin of stationary domain wall enhanced ferroelectric susceptibility. <i>Physical Review B</i> , 2017, 95, .	1.1	15
5	Efficient systematic scheme to construct second-principles lattice dynamical models. <i>Physical Review B</i> , 2017, 95, .	1.1	23
6	Bilayer Polymer Metacomposites Containing Negative Permittivity Layer for New High- <i>k</i> Materials. <i>ACS Applied Materials &amp; Interfaces</i> , 2017, 9, 1793-1800.	4.0	105
7	New insight into the structural evolution of PbTiO <sub>3</sub> : an unbiased structure search. <i>Physical Chemistry Chemical Physics</i> , 2017, 19, 1420-1424.	1.3	5
8	Negative capacitance transients in metal-ferroelectric Hf<sub>0.5</sub>Zr<sub>0.5</sub>O<sub>2</sub>-Insulator-Semiconductor (MFIS) capacitors. , 2017, , .	2	
9	Negative permeability in magnetostatics and its experimental demonstration. <i>Physical Review B</i> , 2017, 96, .	1.1	12
10	Static negative capacitance of a ferroelectric nano-domain nucleus. <i>Applied Physics Letters</i> , 2017, 111, .	1.5	19
11	Evaluation of Negative Capacitance Ferroelectric MOSFET for Analog Circuit Applications. <i>IEEE Transactions on Electron Devices</i> , 2017, 64, 4317-4321.	1.6	70
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13	Transient nature of negative capacitance in ferroelectric field-effect transistors. <i>Solid State Communications</i> , 2017, 265, 12-14.	0.9	22
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15	Phase coexistence and electric-field control of toroidal order in oxide superlattices. <i>Nature Materials</i> , 2017, 16, 1003-1009.	13.3	159
16	On the persistence of polar domains in ultrathin ferroelectric capacitors. <i>Journal of Physics Condensed Matter</i> , 2017, 29, 284001.	0.7	14
17	Nanoscale design of polarization in ultrathin ferroelectric heterostructures. <i>Nature Communications</i> , 2017, 8, 1419.	5.8	80
18	Voltage Drop in a Ferroelectric Single Layer Capacitor by Retarded Domain Nucleation. <i>Nano Letters</i> , 2017, 17, 7796-7802.	4.5	66

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20	Stable charged antiparallel domain walls in hyperferroelectrics. <i>Journal of Physics Condensed Matter</i> , 2017, 29, 244003.	0.7	10
21	Modeling and design considerations for negative capacitance field-effect transistors. , 2017, , .		22
22	Quantum paraelectricity probed by superconducting resonators. <i>Physical Review B</i> , 2017, 95, .	1.1	8
23	Unexpectedly high Curie temperature in weakly strained ferroelectric film. <i>Physica Status Solidi (B): Basic Research</i> , 2017, 254, 1600413.	0.7	3
24	Negative capacitance field effect transistors; capacitance matching and non-hysteretic operation. , 2017, , .		23
25	Differential voltage amplification from ferroelectric negative capacitance. <i>Applied Physics Letters</i> , 2017, 111, .	1.5	36
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32	Domain Wall Orientations in Ferroelectric Superlattices Probed with Synchrotron X-Ray Diffraction. <i>Physical Review Letters</i> , 2018, 120, 037602.	2.9	16
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41	Nanocrystal-Embedded-Insulator Ferroelectric Negative Capacitance FETs with Sub-kT/q Swing. <i>IEEE Electron Device Letters</i> , 2018, , 1-1.	2.2	14
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